

#### HEX INVERTERS WITH SCHMITT TRIGGER INPUTS

### **Description**

The 74AHC14 provides provides six independent Schmitt trigger input inverters with standard push-pull outputs. The device is designed for operation with a power supply range of 2.0V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment.

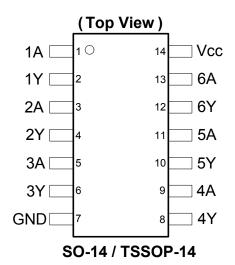
The gates perform the Boolean function:



#### **Features**

- Wide Supply Voltage Range from 2.0V to 5.5 V
- Outputs Sink or Source 8mA at V<sub>CC</sub> = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- Typical hysteresis of 1V allows for transformation of slow changing input signals to sharply defined, fast transition output signals.
- Inputs can be driven by 3.3V or 5.5V allowing for voltage translation applications.
- ESD Protection Exceeds JESD 22
  - 200-V Machine Model (A115-A)
  - 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Pin Assignments**



#### **Applications**

- General Purpose Logic
- Wide array of products such as:
  - PCs, Networking, Notebooks, Netbooks
  - Computer Peripherals, Hard Drives, CD/DVD ROM
  - TV, DVD, DVR, Set Top Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

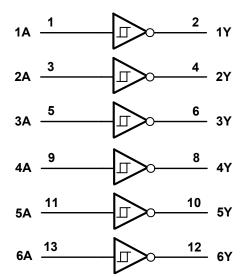
Click here for ordering information, located at the end of datasheet



## **Pin Descriptions**

Pin Number	Pin Name	Function
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	Vcc	Supply Voltage

# **Logic Diagram**



## **Function Table**

Input	Output
Α	Υ
L	Н
Н	L

# **Absolute Maximum Ratings** (Note 4) ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < -0.5V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> < -0.5V	-20	mA
lok	Output Clamp Current V <sub>O</sub> > V <sub>CC</sub> +0.5V	25	mA
Io	Continuous Output Current -0.5V < V <sub>O</sub> V <sub>CC</sub> +0.5V	+/- 25	mA
I <sub>CC</sub>	Continuous Current Through V <sub>CC</sub>	75	mA
I <sub>GND</sub>	Continuous Current Through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

Note:

- Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values. V<sub>CC</sub> to the extent the maximum clamp current is exceeded.
   Unused inputs should be held at V<sub>CC</sub> or Ground.



## Recommended Operating Conditions (Note 5) @T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage		2.0	5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Free-Air Temperature		-40	+125	°C

Note: 5. Unused inputs should be held at  $V_{\text{CC}}$  or Ground.

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Cumb al	Donomoton	Took Conditions	.,	T <sub>A</sub> = -40°0	C to +85°C	T <sub>A</sub> = -40°C	to +125°C	Unit
Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Max	Min	Max	
	Positive-Going		3V		2.2		2.2	
$V_{T+}$	Input Threshold		4.5V		3.15		3.15	V
	Voltage		5.5V		3.85		3.85	
	Negative-Going		3V	0.9		0.9		
$V_{T-}$	Input Threshold		4.5V	1.35		1.35		V
	Voltage		5.5V	1.65		1.65		
	Hystorosis		3V	0.3	1.2	0.25	1.2	
$\Delta V_T$	Hysteresis (V <sub>T+</sub> - V <sub>T-)</sub>		4.5V	0.4	1.4	0.35	1.4	V
	(V + - V -)		5.5V	0.5	1.6	0.45	1.6	
		I <sub>OH</sub> = -50μA	2.0V	1.9		1.9		- - - V
	l	I <sub>OH</sub> = -50μA	3.0V	2.9		2.9		
$V_{OH}$	High Level Output Voltage	I <sub>OH</sub> = -50μA	4.5V	4.4		4.4		
	Voltage	I <sub>OH</sub> = -4mA	3.0V	2.48		2.40		
		I <sub>OH</sub> = -8mA	4.5V	3.80		3.70		
		I <sub>OL</sub> = 50μA	2.0V		0.1		0.1	
		I <sub>OL</sub> = 50μA	3.0V		0.1		0.1	
$V_{OL}$	Low-level Output Voltage	I <sub>OL</sub> = 50μA	4.5V		0.1		0.1	V
	Voltage	I <sub>OL</sub> = 4mA	3.0V		0.44		0.55	
		I <sub>OL</sub> = 8mA	4.5V		0.44		0.55	
Ιį	Input Current	V <sub>I</sub> = GND to 5.5V	3.6V		±1		±2	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC_1} I_O = 0$	3.6V		20		40	μA

## **Operating Characteristics**

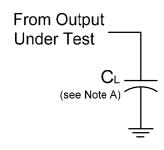
Parameter		Test Conditions	V <sub>CC</sub> = 2.0V Typ	V <sub>CC</sub> = 3.3V Typ	V <sub>CC</sub> = 5V Typ	Unit
C <sub>pd</sub>	Power Dissipation Capacitance per Gate	f = 1MHz	10.4	12.3	13	pF
Ci	Input Capacitance	$V_i = V_{CC} - \text{or GND}$	4.0	4.0	4.0	pF



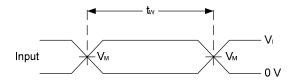
### **Switching Characteristics**

Symbol	Parameter	Test		Test V <sub>A</sub> = +25°C		;	-40°C to +85°C		-40°C to +125°C		Unit
Syllibol	Parameter	Conditions	V <sub>CC</sub>	Min	Тур	Max	Min	Max	Min	Max	Ullit
		Figure 1	3.0V to 3.6V	0.5	4.3	12.8	0.5	15.0	0.5	16.0	
Propaga	Propagation C <sub>L</sub> = 15pF	$C_L = 15pF$	4.5V to 5.5V	0.5	3.2	8.6	0.5	10.0	0.5	11.0	20
t <sub>PD</sub>	Delay A <sub>N</sub> to Y <sub>N</sub>	Figure 1	3.0V to 3.6V	0.5	5.8	16.3	0.5	18.0	0.5	20.5	ns
		$C_L = 50pF$	4.5V to 5.5V	0.5	4.2	10.6	0.5	12.0	0.5	13.5	

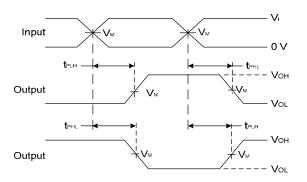
### **Parameter Measurement Information**



V	Inp	outs	V		
Vcc	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	C <sub>L</sub>	
3.3V -3.6V	Vcc	3ns	V <sub>CC</sub> /2	15pF, 50pF	
4.5V to 5.5V	V <sub>CC</sub>	3ns	V <sub>CC</sub> /2	15pF, 50pF	



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

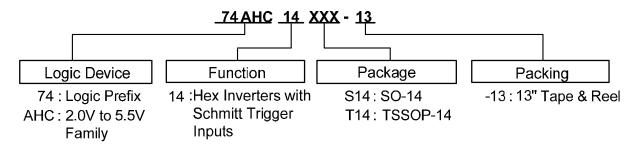
Figure 1 Load Circuit and Voltage Waveforms

Notes: A . Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .



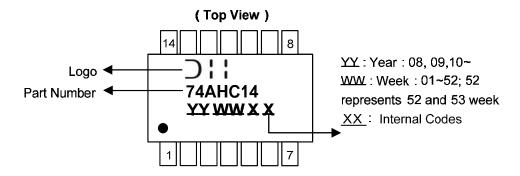
## **Ordering Information**



	Device	Backage Code	Dockoning	7" Tape	and Reel
	Device	Package Code	Packaging	Quantity	Part Number Suffix
	74AHC14S14-13	S14	SO-14	2500/Tape & Reel	-13
,	74AHC14T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

## **Marking Information**

(1) SO-14, TSSOP-14



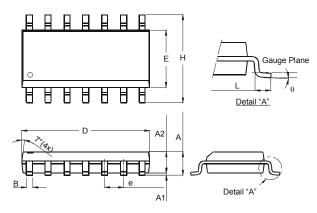
Part Number	Package
74AHC14S14	SO-14
74AHC14T14	TSSOP-14



# Package Outline Dimensions (All dimensions in mm.)

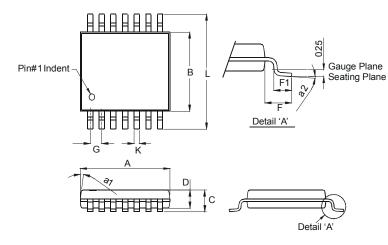
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

#### Package Type: SO-14



	SO-14					
Dim	Min	Max				
Α	1.47	1.73				
A1	0.10	0.25				
A2	1.45	Тур				
В	0.33	0.51				
D	8.53	8.74				
Е	3.80	3.99				
е	1.27	Тур				
Н	5.80	6.20				
L	0.38	1.27				
θ	0°	8°				
All Di	mensions	s in mm				

#### Package Type: TSSOP-14



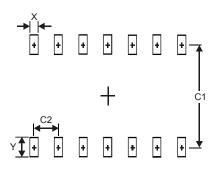
TSSOP-14						
Dim	Min	Max				
a1	7° (	4X)				
a2	0°	8°				
Α	4.9	5.10				
В	4.30	4.50				
С		1.2				
D	8.0	1.05				
F	1.00	Тур				
F1	0.45	0.75				
G	0.65	Тур				
K	0.19	0.30				
L 6.40 Typ						
All Dir	nensions	s in mm				



## **Suggested Pad Layout**

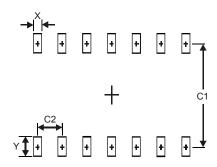
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### Package Type: SO-14



Dimensions	Value (in mm)
X	0.60
Υ	1.50
C1	5.4
C2	1.27

#### Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Υ	1.45
C1	5.9
C2	0.65



#### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

www.diodes.com